

AO4419_003 Information



For Reference Only

Part Number AO4419_003

ManufacturerAlpha & Omega Semiconductor Inc.CategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - Single

DescriptionMOSFET P-CH 30V 9.7A 8SOIC**Package**8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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AO4419_003 Specifications

Manufacturer Part Number AO4419_003 Manufacturer Alpha & Omega Semiconductor Inc. Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package 8-SOIC (0.154", 3.90mm Width) Series - FET Type P-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 30V Current - Continuous Drain (Id) @ 25°C 9.7A (Ta) Drive Voltage (Max Rds On, Min Rds On) 4.5V, 10V Vgs(th) (Max) @ Id 2.7V @ 250μA Gate Charge (Qg) (Max) @ Vgs 32nC @ 10V Input Capacitance (Ciss) (Max) @ Vds 1900pF @ 15V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 3.1W (Ta) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)		
Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package 8-SOIC (0.154", 3.90mm Width) Series - FET Type P-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 30V Current - Continuous Drain (Id) @ 25°C 9.7A (Ta) Drive Voltage (Max Rds On, Min Rds On) 4.5V, 10V Vgs(th) (Max) @ Id 2.7V @ 250μA Gate Charge (Qg) (Max) @ Vgs 32nC @ 10V Input Capacitance (Ciss) (Max) @ Vds 1900pF @ 15V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 3.1W (Ta) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Manufacturer Part Number	AO4419_003
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Package8-SOIC (0.154", 3.90mm Width)Series-FET TypeP-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C9.7A (Ta)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2.7V @ 250μAGate Charge (Qg) (Max) @ Vgs32nC @ 10VInput Capacitance (Ciss) (Max) @ Vds1900pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	Category	Discrete Semiconductor Products
Series - FET Type P-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 30V Current - Continuous Drain (Id) @ 25°C 9.7A (Ta) Drive Voltage (Max Rds On, Min Rds On) 4.5V, 10V Vgs(th) (Max) @ Id 2.7V @ 250μA Gate Charge (Qg) (Max) @ Vgs 32nC @ 10V Input Capacitance (Ciss) (Max) @ Vds 1900pF @ 15V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 3.1W (Ta) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)		Transistors - FETs, MOSFETs - Single
FET Type P-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 30V Current - Continuous Drain (Id) @ 25°C 9.7A (Ta) Drive Voltage (Max Rds On, Min Rds On) 4.5V, 10V Vgs(th) (Max) @ Id 2.7V @ 250µA Gate Charge (Qg) (Max) @ Vgs 32nC @ 10V Input Capacitance (Ciss) (Max) @ Vds 1900pF @ 15V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) 3.1W (Ta) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Package	8-SOIC (0.154", 3.90mm Width)
TechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C9.7A (Ta)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2.7V @ 250μAGate Charge (Qg) (Max) @ Vgs32nC @ 10VInput Capacitance (Ciss) (Max) @ Vds1900pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	Series	-
Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C9.7A (Ta)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2.7V @ 250μAGate Charge (Qg) (Max) @ Vgs32nC @ 10VInput Capacitance (Ciss) (Max) @ Vds1900pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	FET Type	P-Channel
Current - Continuous Drain (Id) @ 25°C9.7A (Ta)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2.7V @ 250μAGate Charge (Qg) (Max) @ Vgs32nC @ 10VInput Capacitance (Ciss) (Max) @ Vds1900pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	Technology	MOSFET (Metal Oxide)
Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2.7V @ 250μAGate Charge (Qg) (Max) @ Vgs32nC @ 10VInput Capacitance (Ciss) (Max) @ Vds1900pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	Drain to Source Voltage (Vdss)	30V
Vgs(th) (Max) @ Id	Current - Continuous Drain (Id) @ 25°C	9.7A (Ta)
Gate Charge (Qg) (Max) @ Vgs Input Capacitance (Ciss) (Max) @ Vds 1900pF @ 15V Vgs (Max) ±20V FET Feature - Power Dissipation (Max) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Input Capacitance (Ciss) (Max) @ Vds Vgs (Max) FET Feature Power Dissipation (Max) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package Package / Case 8-SOIC (0.154", 3.90mm Width)	Vgs(th) (Max) @ Id	2.7V @ 250μA
Vgs (Max)±20VFET Feature-Power Dissipation (Max)3.1W (Ta)Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	Gate Charge (Qg) (Max) @ Vgs	32nC @ 10V
FET Feature - Power Dissipation (Max) 3.1W (Ta) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Input Capacitance (Ciss) (Max) @ Vds	1900pF @ 15V
Power Dissipation (Max) Rds On (Max) @ Id, Vgs 20 mOhm @ 9.7A, 10V Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Vgs (Max)	±20V
Rds On (Max) @ Id, Vgs20 mOhm @ 9.7A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device Package8-SOPackage / Case8-SOIC (0.154", 3.90mm Width)	FET Feature	-
Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Power Dissipation (Max)	3.1W (Ta)
Mounting Type Surface Mount Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Rds On (Max) @ Id, Vgs	20 mOhm @ 9.7A, 10V
Supplier Device Package 8-SO Package / Case 8-SOIC (0.154", 3.90mm Width)	Operating Temperature	-55°C ~ 150°C (TJ)
Package / Case 8-SOIC (0.154", 3.90mm Width)	Mounting Type	Surface Mount
	Supplier Device Package	8-SO
Report errors?	Package / Case	8-SOIC (0.154", 3.90mm Width)
		Report errors?

AO4419_003 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

AO4419_003 Payment Methods



















AO4419_003 Shipping Methods













If you have any question about AO4419_003, please do not hesitate to contact us!

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